

Power management (dual transistors)

UMF8N

2SC5585 and DTC144EE are housed independently in a UMT package.

●Application

Power management circuit

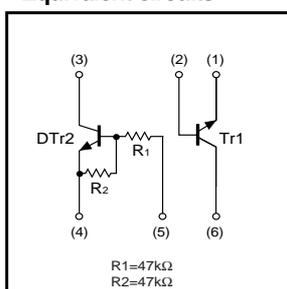
●Features

- 1) Power switching circuit in a single package.
- 2) Mounting cost and area can be cut in half.

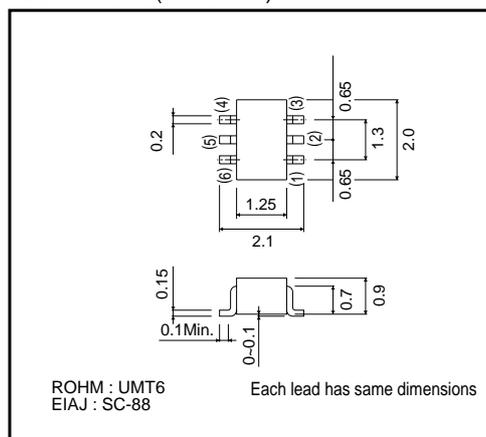
●Structure

Silicon epitaxial planar transistor

●Equivalent circuits



●Dimensions (Units : mm)



●Package, marking, and packaging specifications

Type	UMF8N
Package	UMT6
Marking	F8
Code	TR
Basic ordering unit (pieces)	3000

Transistors

●Absolute maximum ratings (Ta=25°C)

Tr1

Parameter	Symbol	Limits	Unit
Collector-base voltage	V _{CB0}	15	V
Collector-emitter voltage	V _{CEO}	12	V
Emitter-base voltage	V _{EBO}	6	V
Collector current	I _c	500	mA
	I _{CP}	1.0	A *1
Power dissipation	P _C	150(TOTAL)	mW *2
Junction temperature	T _j	150	°C
Range of storage temperature	T _{stg}	-55 to +150	°C

*1 Single pulse P_w=1ms

*2 120mW per element must not be exceeded.

Each terminal mounted on a recommended land.

DTr2

Parameter	Symbol	Limits	Unit
Supply voltage	V _{CC}	50	V
Input voltage	V _{IN}	-10 to +40	V
Collector current	I _c	100	mA *1
Output current	I _o	30	mA
Power dissipation	P _C	150(TOTAL)	mW *2
Junction temperature	T _j	150	°C
Range of storage temperature	T _{stg}	-55 to +150	°C

*1 Characteristics of built-in transistor.

*2 120mW per element must not be exceeded.

Each terminal mounted on a recommended land.

●Electrical characteristics (Ta=25°C)

Tr1

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Collector-emitter breakdown voltage	BV _{CEO}	12	-	-	V	I _c =1mA
Collector-base breakdown voltage	BV _{CB0}	15	-	-	V	I _c =10μA
Emitter-base breakdown voltage	BV _{EBO}	6	-	-	V	I _E =10μA
Collector cut-off current	I _{CB0}	-	-	100	nA	V _{CB} =15V
Emitter cut-off current	I _{EBO}	-	-	100	nA	V _{EB} =6V
Collector-emitter saturation voltage	V _{CE(sat)}	-	100	250	mV	I _c =200mA, I _b =10mA
DC current gain	h _{FE}	270	-	680	-	V _{CE} =2V, I _c =10mA
Transition frequency	f _T	-	320	-	MHz	V _{CE} =2V, I _E =-10mA, f=100MHz
Collector output capacitance	C _{ob}	-	7.5	-	pF	V _{CB} =10V, I _E =0mA, f=1MHz

DTr2

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Input voltage	V _{I(off)}	-	-	0.5	V	V _{CC} =5V, I _o =100μA
	V _{I(on)}	3.0	-	-	V	V _o =0.3V, I _o =2mA
Output voltage	V _{O(on)}	-	100	300	mV	V _o =10mA, I _i =0.5mA
Input current	I _i	-	-	180	μA	V _I =5V
Output current	I _{O(off)}	-	-	500	nA	V _{CC} =50V, V _I =0V
DC current gain	G _i	68	-	-	-	V _o =5V, I _o =5mA
Transition frequency	f _T	-	250	-	MHz	V _{CE} =10V, I _E =5mA, f=100MHz *
Input resistance	R ₁	32.9	47	61.1	kΩ	-
Resistance ratio	R ₂ /R ₁	0.8	1.0	1.2	-	-

*Characteristics of built-in transistor.

Transistors

●Electrical characteristic curves

Tr1

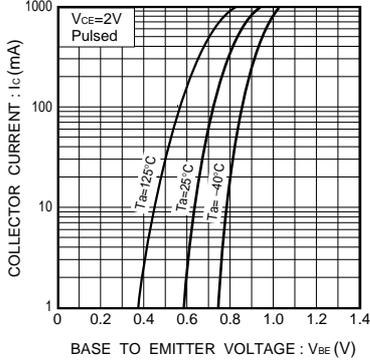


Fig.1 Grounded emitter propagation characteristics

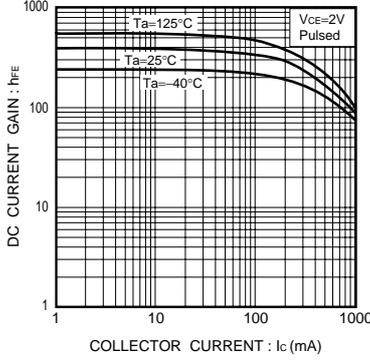


Fig.2 DC current gain vs. collector current

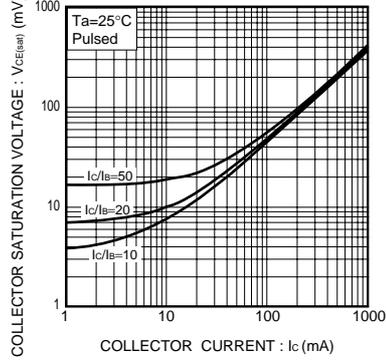


Fig.3 Collector-emitter saturation voltage vs. collector current (I)

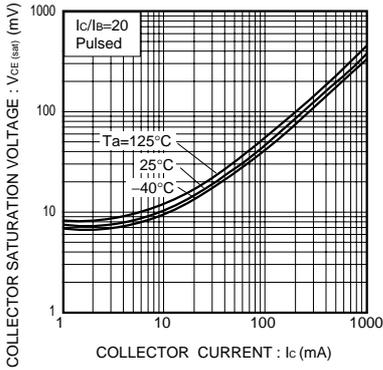


Fig.4 Collector-emitter saturation voltage vs. collector current (II)

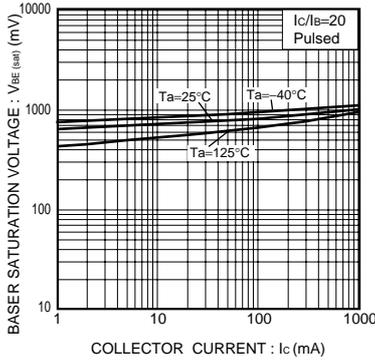


Fig.5 Base-emitter saturation voltage vs. collector current

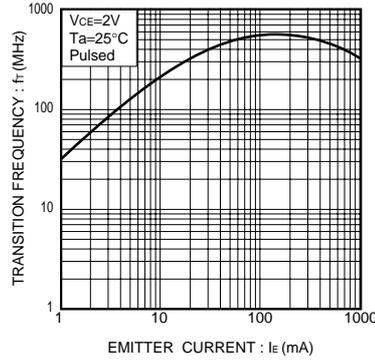


Fig.6 Gain bandwidth product vs. emitter current

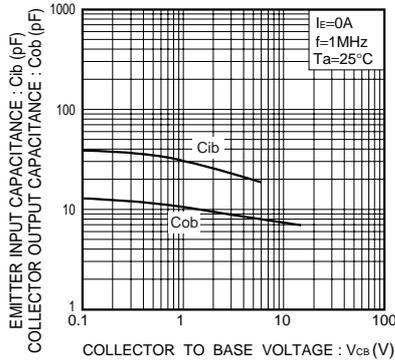


Fig.7 Collector output capacitance vs. collector-base voltage
Emitter input capacitance vs. emitter-base voltage

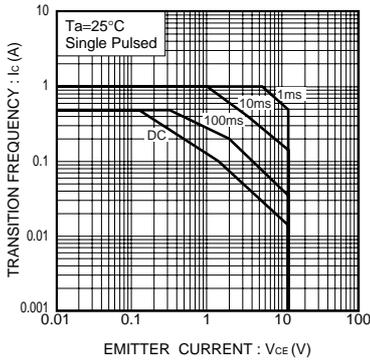


Fig.8 Safe operation area

Transistors

DTr2

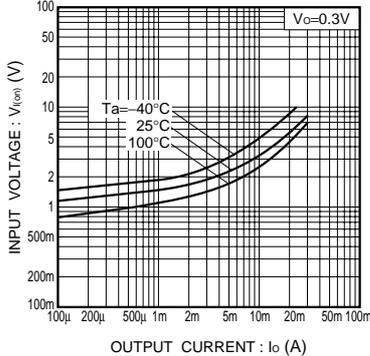


Fig.9 Input voltage vs. output current (ON characteristics)

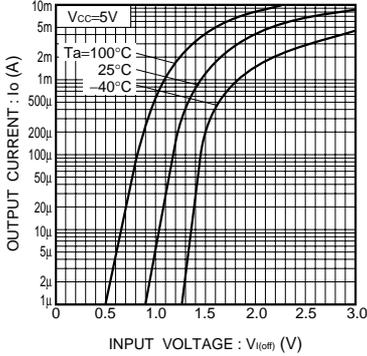


Fig.10 Output current vs. input voltage (OFF characteristics)

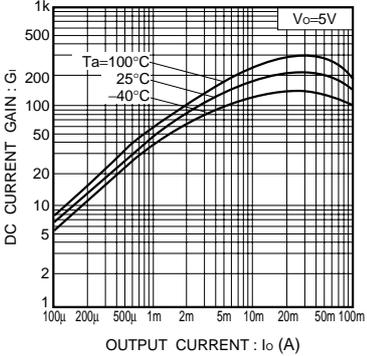


Fig.11 DC current gain vs. output current

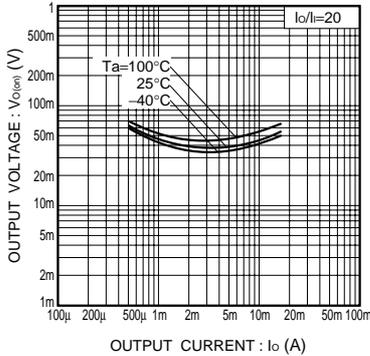


Fig.12 Output voltage vs. output current

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